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# High Speed Infrared Emitting Diodes, 940 nm, GaAlAs, MQW



#### **DESCRIPTION**

VSMB294008 series are infrared, 940 nm emitting diodes in GaAlAs multi quantum well (MQW) technology with high radiant power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

#### **APPLICATIONS**

- · Data transmission
- · Miniature light barrier
- Photointerrupters
- · Optical switch
- · Control and drive circuits
- · Shaft encoders

#### **FEATURES**

Package type: surface mount

• Package form: GW, RGW



• Peak wavelength:  $\lambda_p = 940 \text{ nm}$ 

High reliability

· High radiant power

High radiant intensity

• Angle of half intensity:  $\varphi = \pm 7^{\circ}$ 

· Low forward voltage

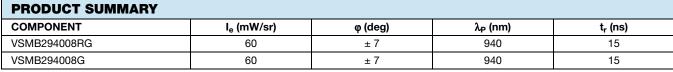
· Suitable for high pulse current operation

• Terminal configurations: gullwing or reserve gullwing

Package matches with detector VEMD2000X01 series

• Floor life: 4 weeks, MSL 2a, acc. J-STD-020

 Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>



#### Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMB294008RG	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMB294008G	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

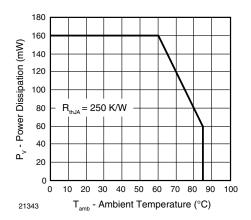
#### Note

• MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V <sub>R</sub>	5	V
Forward current		I <sub>F</sub>	100	mA
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	500	mA
Power dissipation		P <sub>V</sub>	160	mW
Junction temperature		Tj	100	°C
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C
Soldering temperature	according to fig. 10, J-STD-020	T <sub>sd</sub>	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R <sub>thJA</sub>	250	K/W

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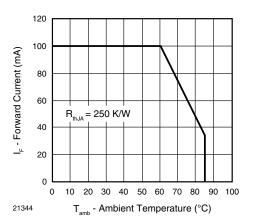


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$V_{F}$	1.15	1.35	1.6	V
	$I_F = 500 \text{ mA}, t_p = 100 \mu \text{s}$	$V_{F}$	=	1.8	-	V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>	-	-0.64	-	mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>	-	-	10	μΑ
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ	=	38	-	pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 100 \mu \text{s}$	l <sub>e</sub>	30	60	90	mW/sr
	$I_F = 500 \text{ mA}, t_p = 100 \mu\text{s}$	l <sub>e</sub>	=	260	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 100 \mu \text{s}$	фe	-	40	-	mW
Temperature coefficient of radiant power	I <sub>F</sub> = 100 mA	TΚφ <sub>e</sub>	-	-0.43	-	%/K
Angle of half intensity		φ	-	± 7	-	deg
Peak wavelength	I <sub>F</sub> = 30 mA	$\lambda_{p}$	920	940	960	nm
Spectral bandwidth	I <sub>F</sub> = 30 mA	Δλ	-	25	-	nm
Temperature coefficient of λ <sub>p</sub>	I <sub>F</sub> = 30 mA	$TK\lambda_p$	-	0.25	-	nm/K
Rise time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>r</sub>	=	15	-	ns
Fall time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>f</sub>	-	15	-	ns
Cut-off frequency	$I_{DC} = 70 \text{ mA}, I_{AC} = 30 \text{ mA pp}$	f <sub>c</sub>	=	23	-	MHz

### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

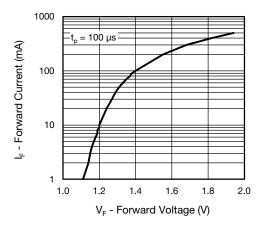


Fig. 3 - Forward Current vs. Forward Voltage

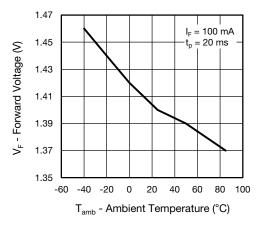


Fig. 4 - Forward Voltage vs. Ambient Temperature

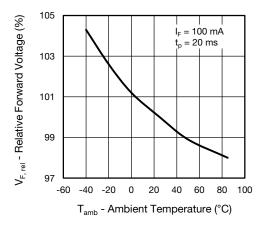


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

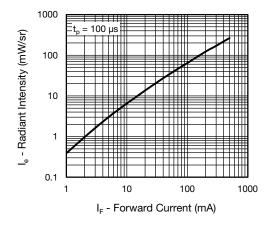


Fig. 6 - Radiant Intensity vs. Forward Current

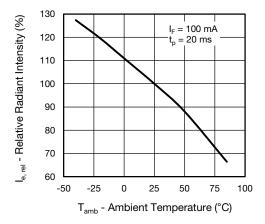


Fig. 7 - Radiant Intensity vs. Ambient Temperature

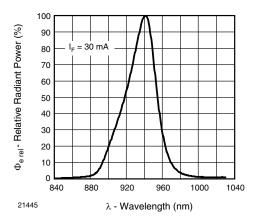


Fig. 8 - Relative Radiant Power vs. Wavelength

## VSMB294008RG, VSMB294008G

### Vishay Semiconductors

### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

Conditions:  $T_{amb}$  < 30 °C, RH < 60 %

Moisture sensitivity level 2a, acc. to J-STD-020.

### **DRYING**

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40  $^{\circ}$ C (+ 5  $^{\circ}$ C), RH < 5  $^{\circ}$ M.

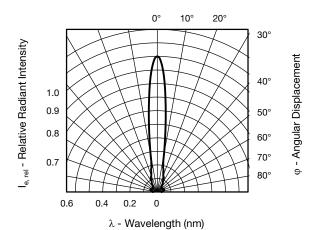


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

#### **SOLDER PROFILE**

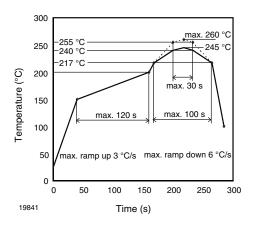
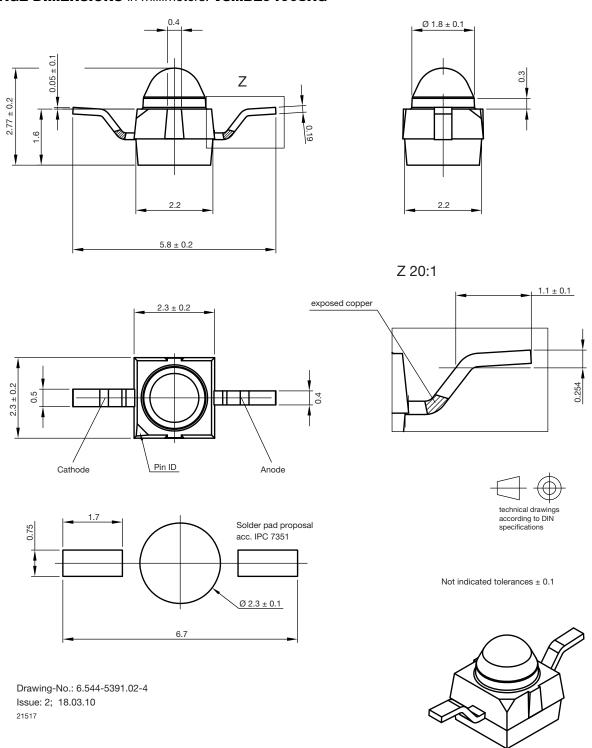
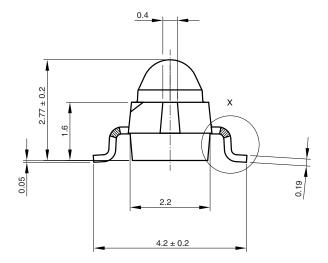


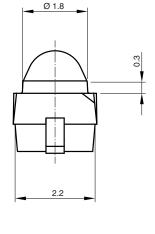
Fig. 10 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

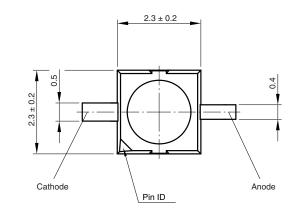
### **PACKAGE DIMENSIONS** in millimeters: **VSMB294008RG**

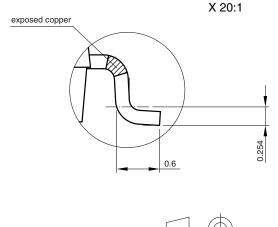


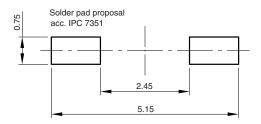
### PACKAGE DIMENSIONS in millimeters: VSMB294008G







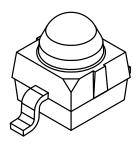




Not indicated tolerances ± 0.1

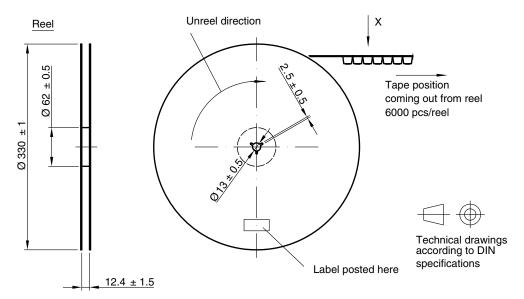
technical drawings according to DIN specifications

Drawing-No.: 6.544-5383.02-4 Issue: 4; 18.03.10

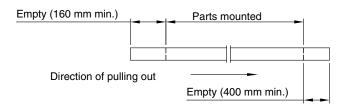




### TAPING AND REEL DIMENSIONS in millimeters: VSMB294008RG

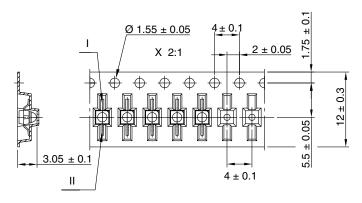


Leader and trailer tape:



### Terminal position in tape

Devicce	Lead I	Lead II
VEMT2000		
VEMT2500	Collector	Emitter
VEMD2000		
VEMD2500	0-4	AI -
VSMB2000	Cathode	Anode
VSMG2000		
VSMY2850RG	Anode	Cathode

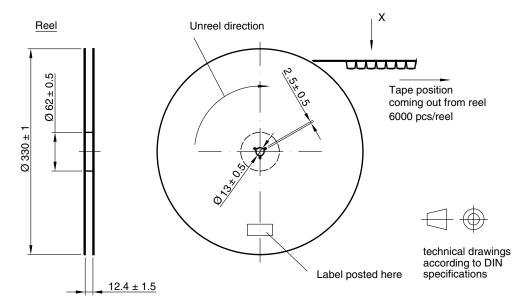


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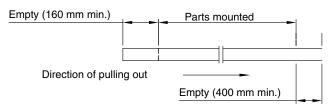
Issue: 2; 18.03.10

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### TAPING AND REEL DIMENSIONS in millimeters: VSMB294008G

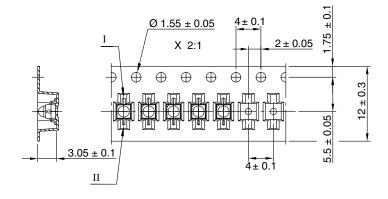


### Leader and trailer tape:



### Terminal position in tape

Devicce	Lead I	Lead II
VEMT2020		
VEMT2520	Collector	Emitter
VSMB2020		
VSMG2020	Cathada	Anada
VEMD2020	Cathode	Anode
VEMD2520		
VSMY2850G	Anode	Cathode



Drawing-No.: 9.800-5091.01-4

Issue: 3; 18.03.10

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